

### **MMBD7000W**

# SURFACE MOUNT FAST SWITCHING DIODE

### REVERSE VOLTAGE – 100 Volts FORWARD CURRENT – 0.2 Ampere

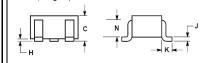
**SOT-323** 

#### **FEATURES**

- Fast Switching Speed
- Ideally suited for automatic insertion
- For general purpose switching applications

#### **MECHANICAL DATA**

- Case: SOT-323 Plastic
- Case Material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Moisture Sensitivity: Level 1 per J-STD-020D
- Lead Free in RoHS 2002/95/EC Compliant



SOT-323				
Min.	Max.			
1.80	2.20			
1.15	1.35			
0.80	1.00			
0.30	0.40			
1.20	1.40			
0.00	0.10			
0.10	0.25			
0.425 Ref.				
0.650 Bsc				
0.700 Ref.				
2.00	2.40			
	Min. 1.80 1.15 0.80 0.30 1.20 0.00 0.10 0.425 0.650 0.700			

Dimensions in millimeter

#### Maximum Ratings & Thermal Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

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Characteristic	Symbol	MMBD7000W	Units
Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	100	V
Forward Current	I <sub>F</sub>	200	mA
Peak Forward Surge Current	I <sub>FM</sub>	500	mA
Power Dissipation	P <sub>D</sub>	225	mW
Thermal Resistance Junction to Ambient	R⊕JA	417	°C/W
Operating Temperature Range	T <sub>J</sub>	150	$^{\circ}\!\mathbb{C}$
Storage Temperature Range	T <sub>STG</sub>	-55~+150	°C

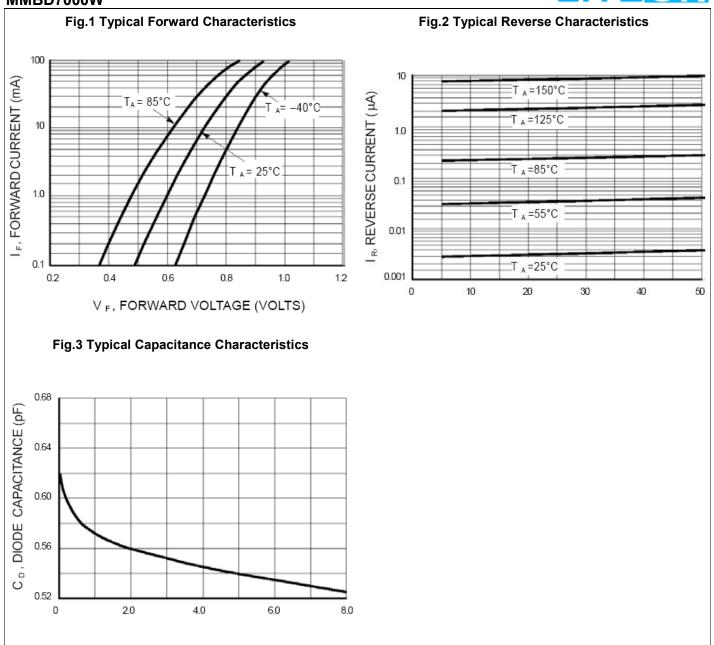
#### Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Test Condition	Symbol	MMBD7000W	Unit
Reverse Breakdown Voltage	I <sub>R</sub> = 100uA	$V_{BR}$	100	V
Maximum Forward Voltage	I <sub>F</sub> = 1mA I <sub>F</sub> = 10mA I <sub>F</sub> = 100mA	V <sub>F</sub>	0.7 0.82 1.1	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	$V_R = 50V$ $V_R = 100V$ $V_R = 50V, 125^{\circ}C$	I <sub>R</sub>	1 3 100	uA
Typical Diode Capacitance	V <sub>R</sub> =0V,f=1MHz	C <sub>D</sub>	1.5	pF
Reverse Recovery time	I <sub>F</sub> =I <sub>R</sub> =10mA,	trr	4	nS

REV. 0, Jan-2013, KSYR93

# RATING AND CHARACTERISTIC CURVES MMBD7000W





#### **Device Marking:**

Device P/N	Marking	Equivalent Circuit Diagram
MMBD7000W	M5C	3 0 0 1 0 2



## **Important Notice and Disclaimer**

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# **New Marking Rule Notification**

Range: In order to have well management in process control, the new marking rule is applied to small signal device including Switching Diode, Transistor and Schottky Diode.

Package: SOT-23 / SOT-323 / SOT-523

